

KBPC3506T/W thru KBPC3510T/W

Single Phase Silicon Bridge Rectifier

 $V_{RRM} = 600 \text{ V} - 1000 \text{ V}$ $I_{O} = 35 \text{ A}$

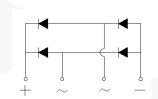
Features

- · High efficiency
- Silicon junction
- Metal case
- \bullet Types from 600 V to 1000 V V_{RRM}
- Not ESD Sensitive

Mechanical Data

Case: Mounted in the bridge encapsulation

Mounting: Hole for #10 screw Polarity: Marked on case



KBPC-T/W Package





Maximum ratings at Tc = 25 °C, unless otherwise specified (KBPCXXXXT uses KBPC-T package while KBPCXXXXW uses KBPC-W package)

| Parameter | Symbol | Conditions | KBPC3506T/W | KBPC3508T/W | KBPC3510T/W | Unit |
|----------------------------|------------------------|------------|-------------|-------------|-------------|------|
| Repetitive peak reverse vo | ltage V _{RRM} | | 600 | 800 | 1000 | V |
| RMS reverse voltage | V_{RMS} | | 420 | 560 | 700 | V |
| DC blocking voltage | V_{DC} | | 600 | 800 | 1000 | V |
| Operating temperature | Tj | | -55 to 150 | -55 to 150 | -55 to 150 | °C |
| Storage temperature | T_{stg} | | -55 to 150 | -55 to 150 | -55 to 150 | °C |

Electrical characteristics at Tc = 25 °C, unless otherwise specified

Single phase, half sine wave, 60 Hz, resistive or inductive load

For capacitive load derate current by 20%

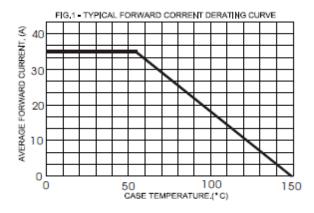
| Parameter | Symbol | Conditions | KBPC3506T/W | KBPC3508T/W | KBPC3510T/W | Unit |
|---|------------------|-------------------------|-------------|-------------|-------------|------|
| Maximum average forward rectified current | I _O | T _c = 55 °C | 35 | 35 | 35 | А |
| Peak forward surge current | I _{FSM} | 8.3 ms half sine-wave | 400 | 400 | 400 | Α |
| Maximum instantaneous forward voltage per leg | V_{F} | I _F = 17.5 A | 1.1 | 1.1 | 1.1 | V |
| Maximum DC reverse current at | I _R | T _c = 25 °C | 5 | 5 | 5 | μА |
| rated DC blocking voltage per leg | | $T_c = 100 ^{\circ}C$ | 500 | 500 | 500 | |
| Typical junction capacitance ¹ | C _j | | 300 | 300 | 300 | pF |
| Thermal characteristics | | | | | | |
| Typical thermal resistance ² | R _{⊝JC} | | 1.4 | 1.4 | 1.4 | °C/W |

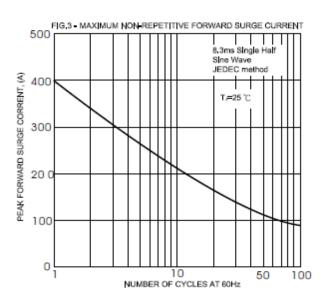
¹ - Measured ay 1 MHz and applied reverse voltage of 4.0 V D.C.

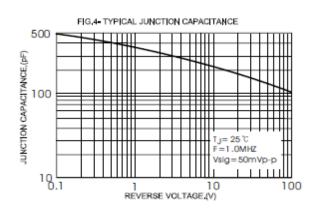
² - Device mounted on 300 mm x 300 mm x 1.6 mm Cu plate heatsink

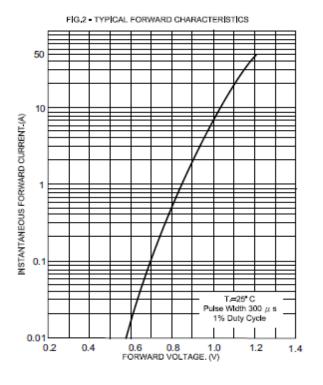


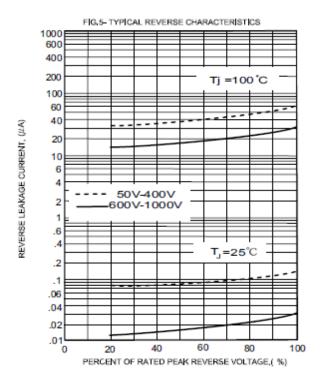
KBPC3506T/W thru KBPC3510T/W









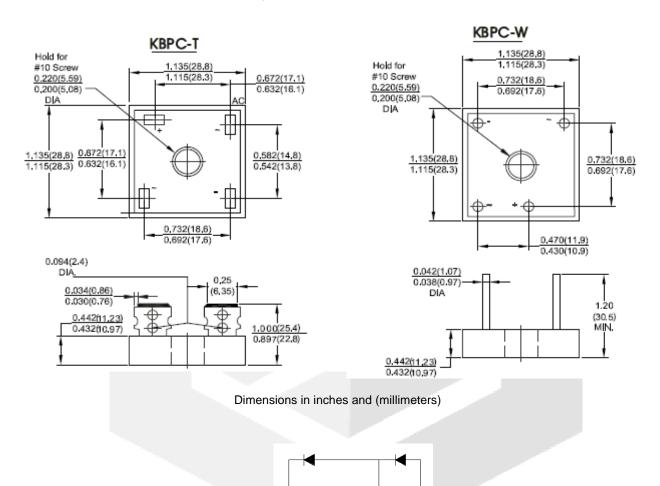




KBPC3506T/W thru KBPC3510T/W

Package dimensions and terminal configuration

Product is marked with part number and terminal configuration.



Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

Navitas Semiconductor:

KBPC3510T